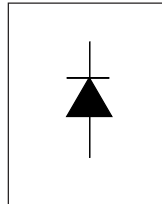


**SURFACE MOUNTABLE
FAST SOFT RECOVERY
DIODE**



V_F	< 1.2V @ 8A
t_{rr}	= 55ns
V_{RRM}	200 to 600V

Description/Features

The 8EWF..S fast soft recovery **QUIETIR** rectifier series has been optimized for combined short reverse recovery time, low forward voltage drop and low leakage current

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

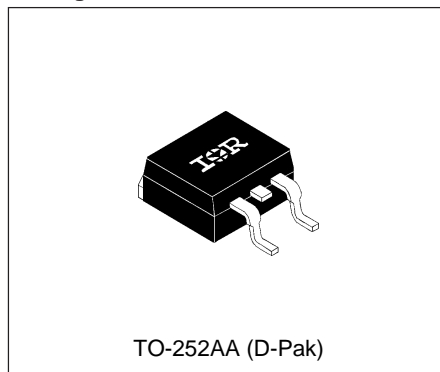
Typical applications are both:

- Output rectification and freewheeling diode in inverters, choppers and converters.
- Input rectifications where severe restrictions on conducted EMI should be met.

Major Ratings and Characteristics

Characteristics	8EWF..S	Units
$I_{F(AV)}$ Sinusoidal waveform	8	A
V_{RRM}	200 to 600	V
I_{FSM}	170	A
V_F @ 8A, $T_J=25^\circ\text{C}$	1.2	V
t_{rr} @ 1A, 100A/ μs	55	ns
T_J	-40 to 150	$^\circ\text{C}$

Package Outline



Voltage Ratings

Part Number	V_{RRM} maximum peak reverse voltage V	V_{RSM} maximum non repetitive peak reverse voltage V	I_{RRM} 150°C mA
8EWF02S	200	300	3
8EWS04S	400	500	
8EWF06S	600	700	

Absolute Maximum Ratings

Parameters	8EWF..S	Units	Conditions
$I_{F(AV)}$ Max. Average Forward Current	8	A	@ $T_c = 96^\circ\text{C}$, 180° conduction half sine wave
I_{FSM} Max. Peak One Cycle Non-Repetitive Surge Current	170	A	10ms Sine pulse, rated V_{RRM} applied
	200		10ms Sine pulse, no voltage reapplied
I^2t Max. I^2t for fusing	140	A^2s	10ms Sine pulse, rated V_{RRM} applied
	200		10ms Sine pulse, no voltage reapplied
$I^2\sqrt{t}$ Max. $I^2\sqrt{t}$ for fusing	2000	A^2/s	$t = 0.1$ to 10ms, no voltage reapplied

Electrical Specifications

Parameters	8EWF..S	Units	Conditions	
V_{FM} Max. Forward Voltage Drop	1.2	V	@ 8A, $T_J = 25^\circ\text{C}$	
r_t Forward slope resistance	16	$\text{m}\Omega$	$T_J = 150^\circ\text{C}$	
$V_{F(TO)}$ Threshold voltage	1.13	V		
I_{RM} Max. Reverse Leakage Current	0.1	mA	$T_J = 25^\circ\text{C}$	$V_R = \text{rated } V_{RRM}$
	3		$T_J = 150^\circ\text{C}$	

Typical Reverse Recovery Characteristics

Parameters	8EWF..S	Units	Conditions	
t_{rr} Reverse Recovery Time	140	ns	$I_F @ 8\text{Apk}$	
I_{tr} Reverse Recovery Current	2.6	A	@ 25A/ μs	
Q_{rr} Reverse Recovery Charge	0.25	μC	@ $T_J = 25^\circ\text{C}$	
S Snap Factor	t_b/t_a	-		

Thermal-Mechanical Specifications

Parameters	8EWF..S	Units	Conditions
T _J Max. Junction Temperature Range	-40 to 150	°C	
T _{stg} Max. Storage Temperature Range	-40 to 150	°C	
Soldering Temperature	240	°C	for 10 seconds
R _{thJC} Max. Thermal Resistance Junction to Case	2.5	°C/W	DC operation
R _{thJA} Typ. Thermal Resistance Junction to Ambient (PCB Mount)**	50	°C/W	
wt Approximate Weight	1(0.03)	g(oz.)	
T Case Style	TO-252AA(D-Pak)		

**When mounted on 1" square (650mm²) PCB of FR-4 or G-10 material 4 oz (140µm) copper 40°C/W
For recommended footprint and soldering techniques refer to application note #AN-994

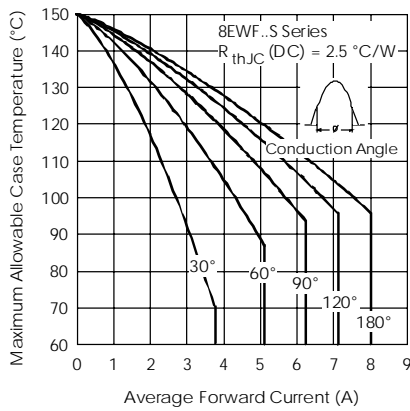


Fig. 1 - Current Rating Characteristics

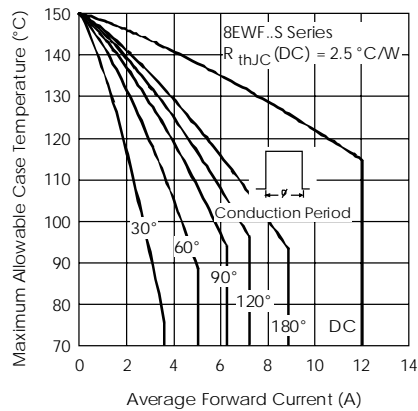


Fig. 2 - Current Rating Characteristics

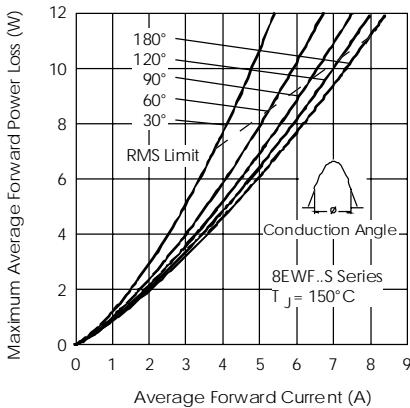


Fig. 3 - Forward Power Loss Characteristics

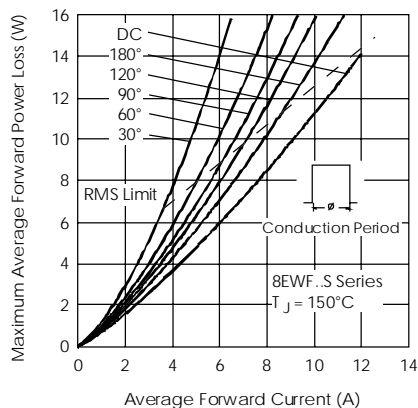


Fig. 4 - Forward Power Loss Characteristics

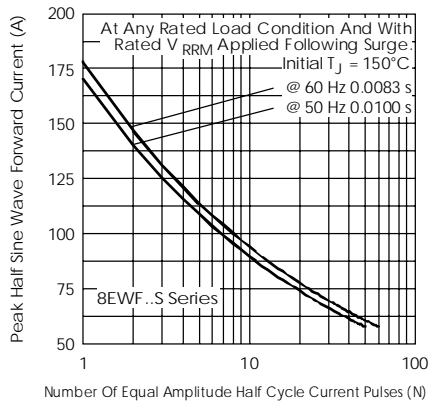


Fig. 5 - Maximum Non-Repetitive Surge Current

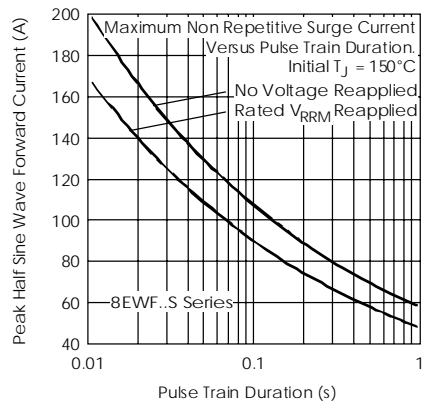


Fig. 6 - Maximum Non-Repetitive Surge Current

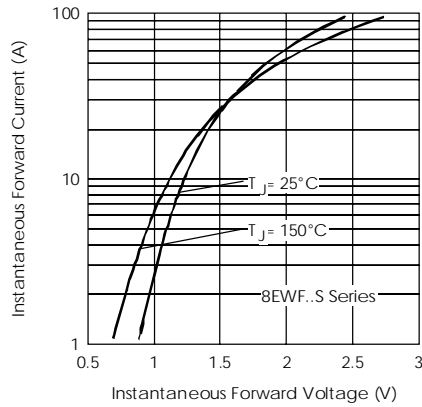


Fig. 7 - Forward Voltage Drop Characteristics

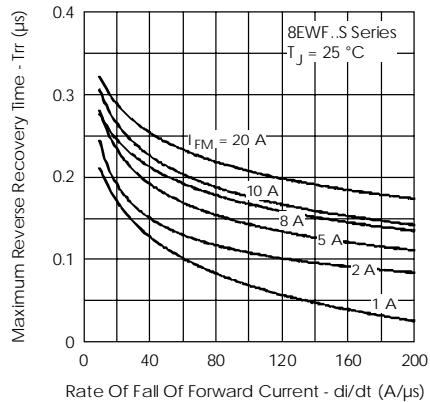


Fig. 8 - Recovery Time Characteristics, $T_J = 25^\circ\text{C}$

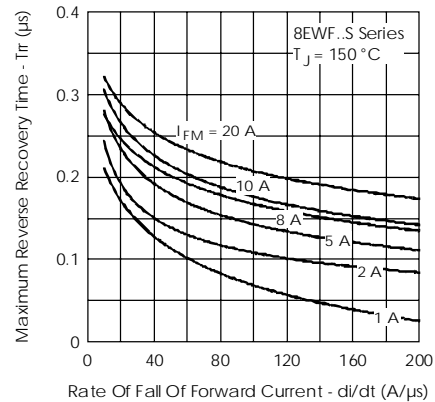


Fig. 9 - Recovery Time Characteristics, $T_J = 150^\circ\text{C}$

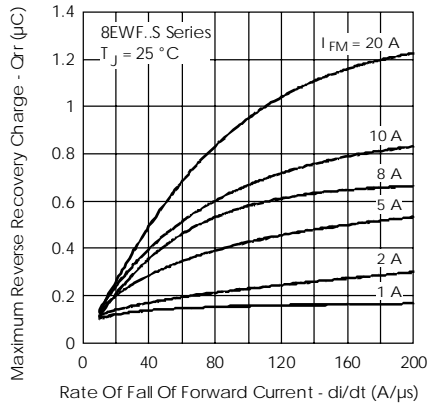


Fig. 10-Recovery Charge Characteristics, $T_j = 25^\circ\text{C}$

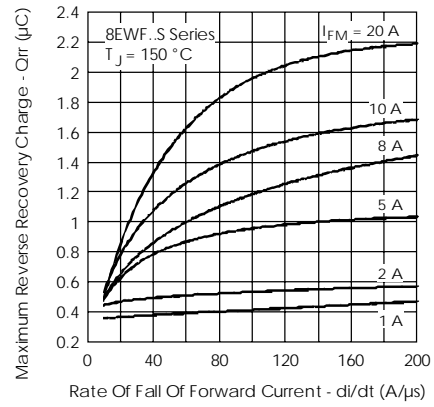


Fig. 11-Recovery Charge Characteristics, $T_j = 150^\circ\text{C}$

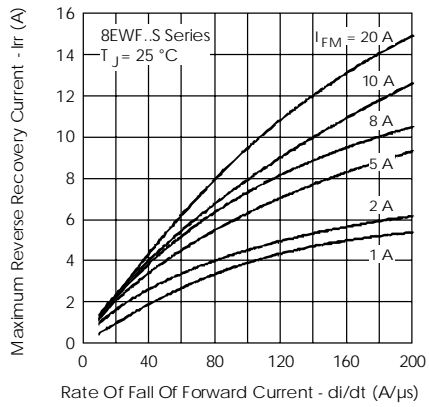


Fig. 12-Recovery Current Characteristics, $T_j = 25^\circ\text{C}$

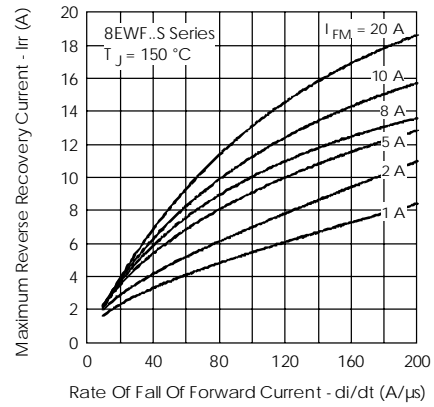


Fig. 13-Recovery Current Characteristics, $T_j = 150^\circ\text{C}$

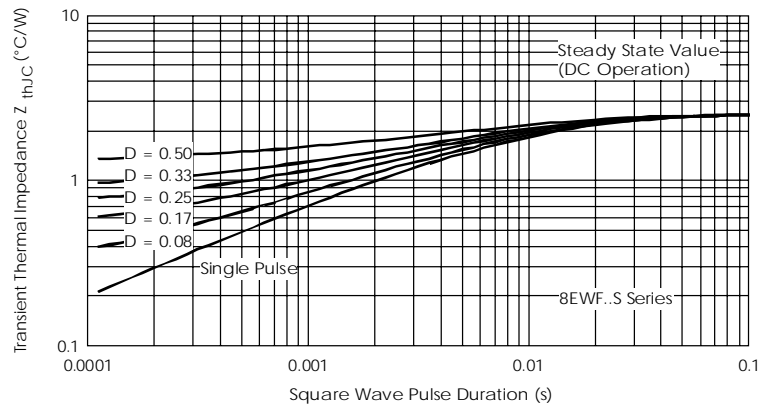


Fig. 14-Thermal Impedance Z_{thjC} Characteristics

Ordering Information Table

Device Code

8	E	W	F	06	S	TRL
①	②	③	④	⑤	⑥	⑦

1 - Current Rating

2 - Circuit Configuration:
E = Single Diode

3 - Package:
W = D-Pak

4 - Type of Silicon:
F = Fast Soft Recovery Rectifier

5 - Voltage code: Code x 100 = V_{RRM}

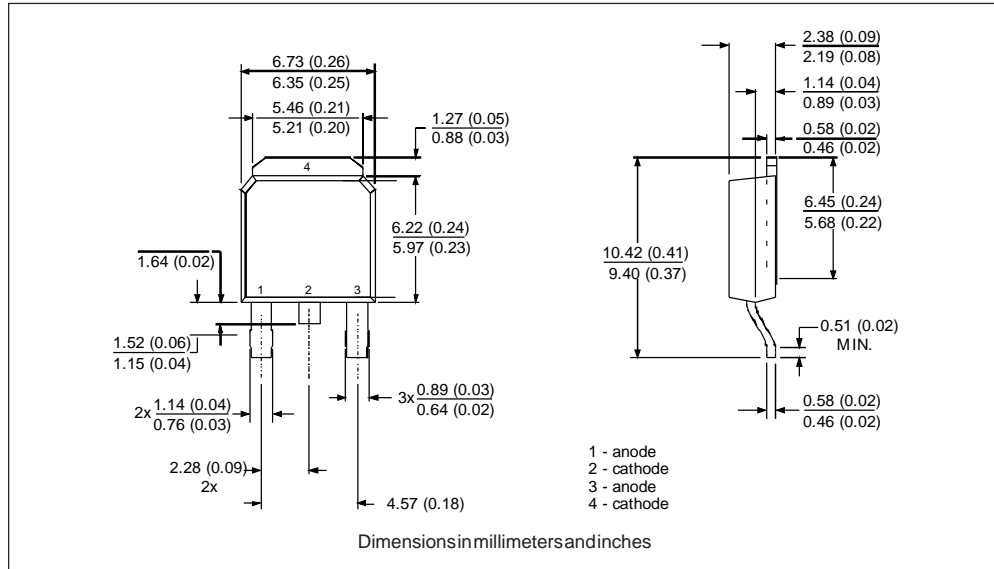
6 - S = Surface Mountable

7 - Tape and Reel Option:
TRL = Left Orientation Reel
TRR = Right Orientation Reel

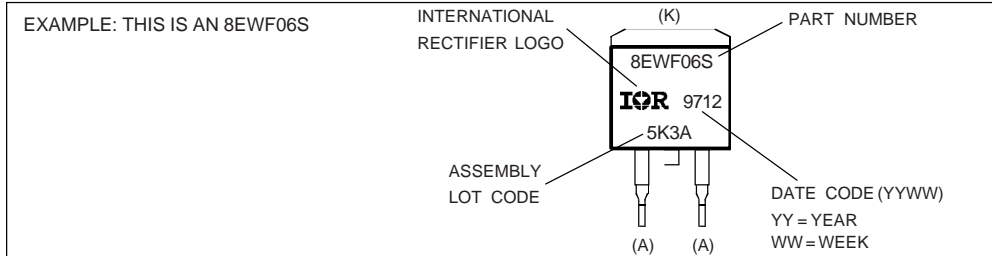
02 = 200V
 04 = 400V
 06 = 600V

BASE
Cathode 2
Anode 1 Anode 3

Outline Table



Marking Information



Tape & Reel Information

